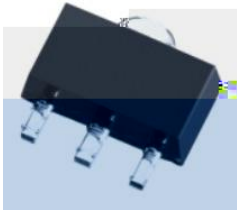
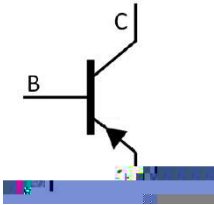


Silicon PNP transistor in a SOT-89 Plastic Package.

Suitable for output stage of 3 watts amplifier, small flat package, complementary to 2SC2883.

Audio frequency amplifier applications.



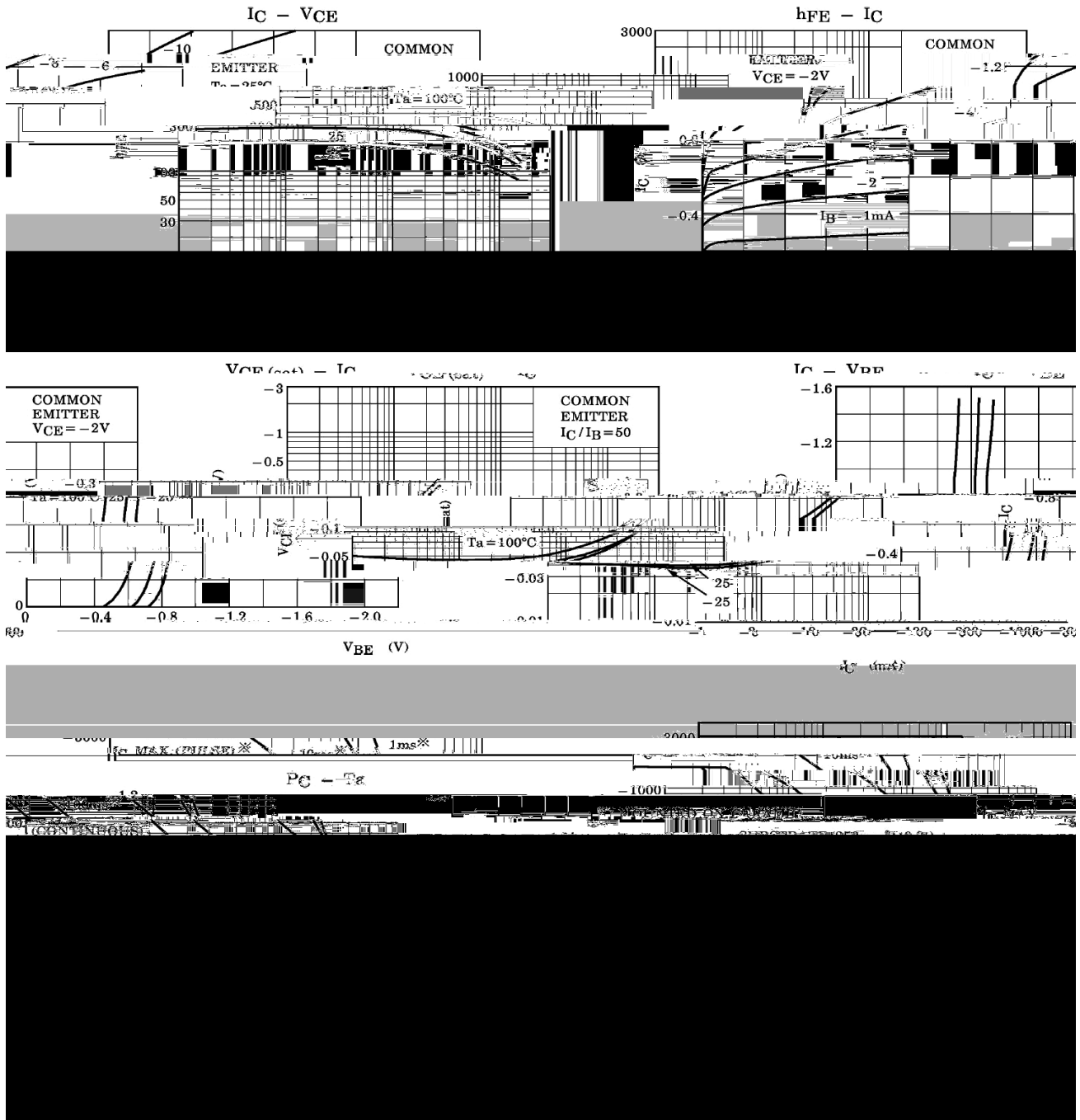
PIN1 Base PIN 2 Collector PIN 3 Emitter

h_{FE} Classifications Symbol	O	Y
h_{FE} Range	100 200	160 320
Marking	HHO	HHY

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-30	V
Collector to Emitter Voltage	V_{CEO}	-30	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current-Continuous	I_C	-1.5	A
Collector Base-Continuous	I_B	-0.3	A
Collector Power Dissipation	P_C	500	mW
Collector Power Dissipation*	$*P_C$	1.0	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

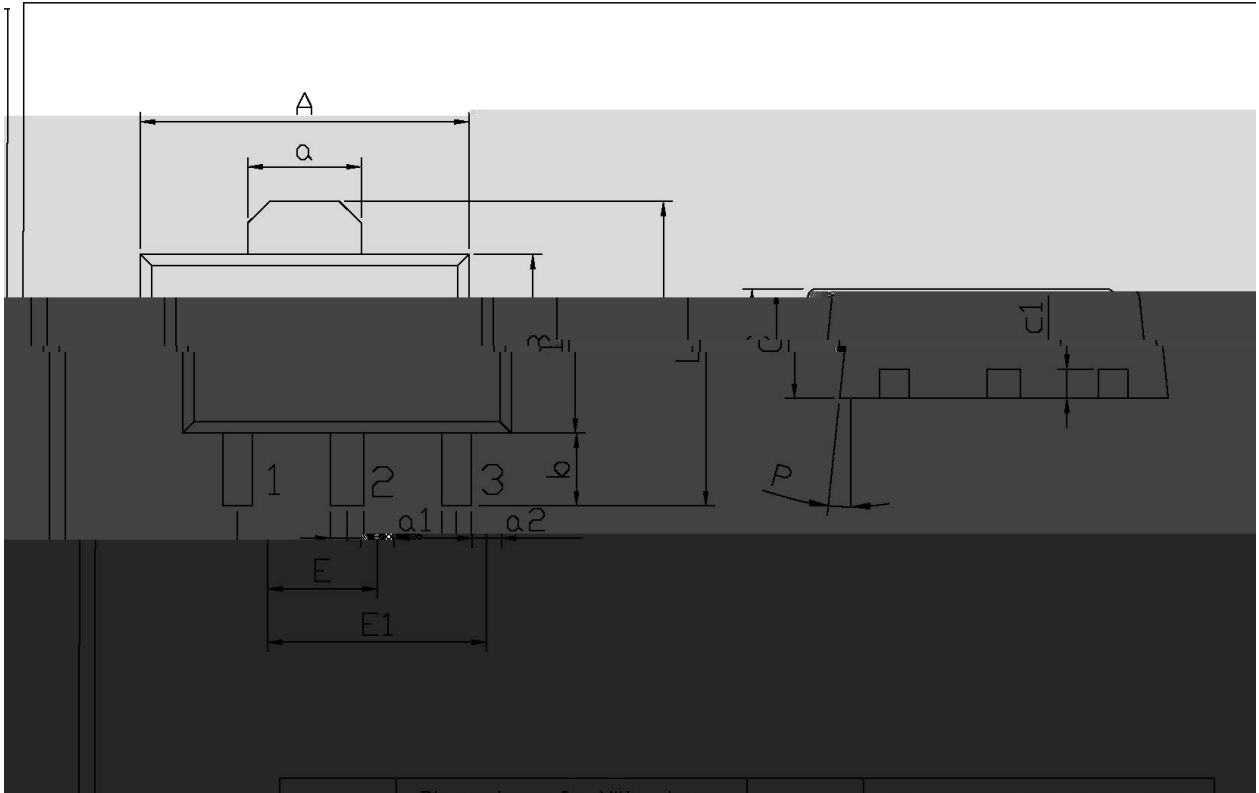
*mounted on ceramic substrate(250mm²x0.8t)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_{150 2}$				

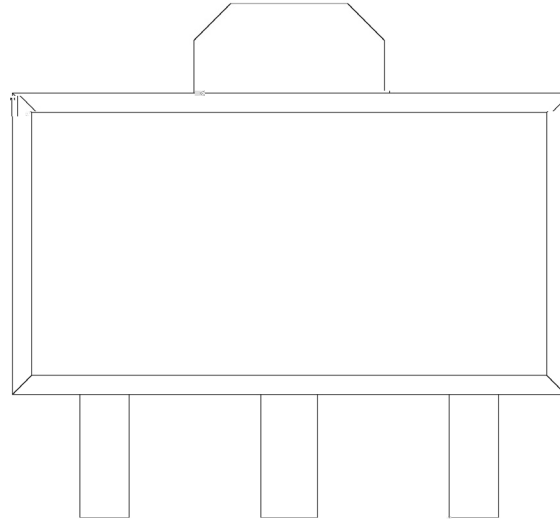


SOT-883

单位: mm



DIMENSIONS IN MILLIMETERS			DIMENSIONS IN MILLIMETERS		
Symbol	Min	Max	Symbol	Min	Max
A	4.4	4.7	a1	0.36	0.4
a	1.2	1.4	a2	0.36	0.4
b	0.3	0.4	E	0.8	1.0
E1	0.8	1.0	P	0.07	0.08
U	0.15	0.18			



H

H

O h_{FE}

Note:

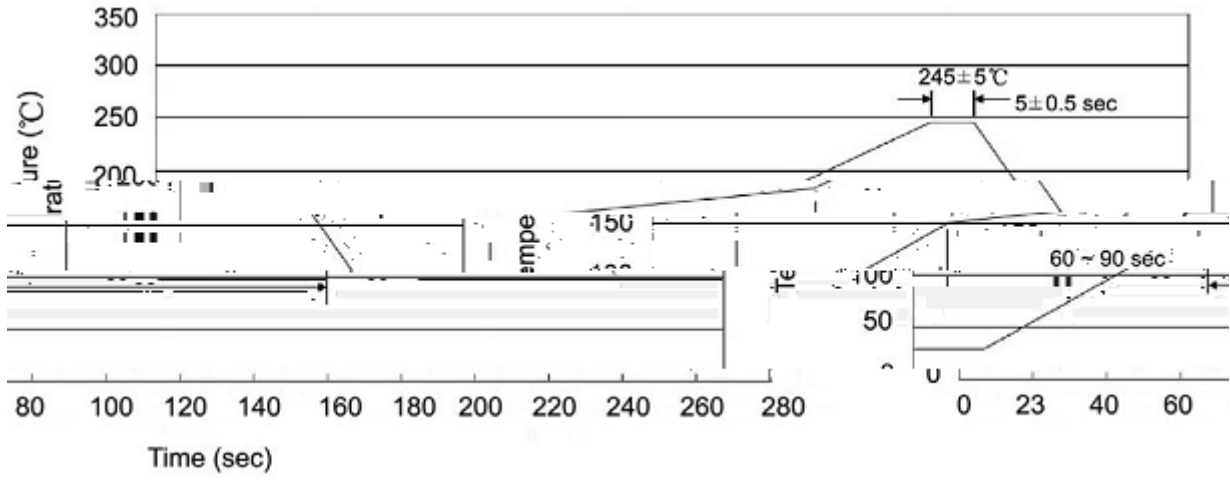
H: Company Code.

H: Product Type.

O: h_{FE} Classifications Symbol

**:

K\d g\iXk i\`Gif]`d `]fi`@ `I \]fn `Jfd \i'e^ZGS=i\z



Note:

1 25 150 60 90sec;

1.Preheating:25~150